

### • Product Summary

| Part #   | $V_{DS}$ | $R_{DS(on).typ}$<br>(@ $V_{GS}=10V$ ) | $R_{DS(on).typ}$<br>(@ $V_{GS}=4.5V$ ) | $I_D$ |
|----------|----------|---------------------------------------|----------------------------------------|-------|
| EFM3422A | 60V      | 120m $\Omega$                         | 135m $\Omega$                          | 2.5A  |

### • Features

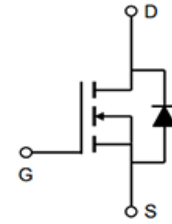
- Low  $R_{DS(on)}$  @  $V_{GS}=10V$
- 4.5V Logic Level Control
- N Channel SOT23-3L Package
- Pb-Free, RoHS Compliant

### • Application

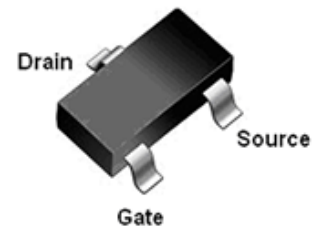
- Load Switch
- Battery switch
- DC/DC Converter

### • Ordering Information:

|                           |           |
|---------------------------|-----------|
| Part NO.                  | EFM3422A  |
| Marking                   | AR****    |
| Packing Information       | REEL TAPE |
| Basic ordering unit (pcs) | 3000      |



N- Channel MOSFET



SOT23-3L



### • Absolute Maximum Ratings ( $T_C=25^{\circ}C$ )

| Parameter                                        | Symbol         | Limit      | Unit        |
|--------------------------------------------------|----------------|------------|-------------|
| Drain-Source Voltage                             | $V_{DS}$       | 60         | V           |
| Gate-Source Voltage                              | $V_{GS}$       | $\pm 20$   | V           |
| Drain Current-Continuous                         | $I_D$          | 2.5        | A           |
| Drain Current-Pulsed <sup>(Note 1)</sup>         | $I_{DM}$       | 12         | A           |
| Maximum Power Dissipation                        | $P_D$          | 1.56       | W           |
| Operating Junction and Storage Temperature Range | $T_J, T_{STG}$ | -55 To 150 | $^{\circ}C$ |

### • Thermal Characteristic

|                                                             |                 |    |               |
|-------------------------------------------------------------|-----------------|----|---------------|
| Thermal Resistance, Junction-to-Ambient <sup>(Note 2)</sup> | $R_{\theta JA}$ | 80 | $^{\circ}C/W$ |
|-------------------------------------------------------------|-----------------|----|---------------|

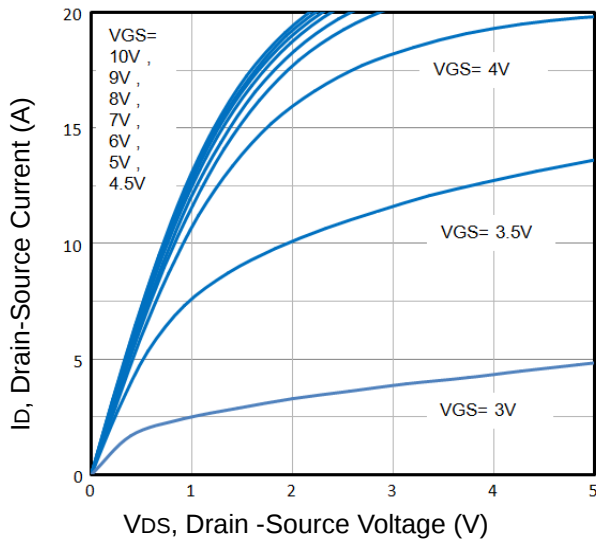
• Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)

| Parameter                          | Symbol              | Condition                                                                             | Min | Typ  | Max  | Unit |
|------------------------------------|---------------------|---------------------------------------------------------------------------------------|-----|------|------|------|
| Off Characteristics                |                     |                                                                                       |     |      |      |      |
| Drain-Source Breakdown Voltage     | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V I <sub>D</sub> =250uA                                             | 60  | --   | --   | V    |
| Zero Gate Voltage Drain Current    | I <sub>DSS</sub>    | V <sub>DS</sub> =60V V <sub>GS</sub> =0V                                              | --  | --   | 1    | μA   |
| Gate-Body Leakage Current          | I <sub>GSS</sub>    | V <sub>GS</sub> =±20V V <sub>DS</sub> =0V                                             | --  | --   | ±100 | nA   |
| On Characteristics (Note 3)        |                     |                                                                                       |     |      |      |      |
| Gate Threshold Voltage             | V <sub>GS(th)</sub> | V <sub>DS</sub> =V <sub>GS</sub> I <sub>D</sub> =250uA                                | 1.0 | 1.3  | 2.0  | V    |
| Drain-Source On-State Resistance   | R <sub>DS(ON)</sub> | V <sub>GS</sub> =10V I <sub>D</sub> =2.5A                                             | --  | 120  | 135  | mΩ   |
|                                    |                     | V <sub>GS</sub> =4.5V I <sub>D</sub> =2A                                              | --  | 135  | 145  | mΩ   |
| Dynamic Characteristics (Note4)    |                     |                                                                                       |     |      |      |      |
| Input Capacitance                  | C <sub>Iss</sub>    | V <sub>DS</sub> =30V V <sub>GS</sub> =0V<br><br>F=1.0MHz                              | --  | 283  | --   | PF   |
| Output Capacitance                 | C <sub>Oss</sub>    |                                                                                       | --  | 18   | --   | PF   |
| Reverse Transfer Capacitance       | C <sub>rss</sub>    |                                                                                       | --  | 13   | --   | PF   |
| Gate Resistance                    | R <sub>g</sub>      | F=1.0MHz                                                                              | --  | 9    | --   | Ω    |
| Switching Characteristics (Note 4) |                     |                                                                                       |     |      |      |      |
| Turn-on Delay Time                 | t <sub>d(on)</sub>  | V <sub>DD</sub> =30V I <sub>D</sub> =1A<br>V <sub>GS</sub> =10V R <sub>G</sub> =3.3Ω, | --  | 3.4  | --   | nS   |
| Turn-on Rise Time                  | t <sub>r</sub>      |                                                                                       | --  | 5.8  | --   | nS   |
| Turn-Off Delay Time                | t <sub>d(off)</sub> |                                                                                       | --  | 21   | --   | nS   |
| Turn-Off Fall Time                 | t <sub>f</sub>      |                                                                                       | --  | 4.6  | --   | nS   |
| Total Gate Charge                  | Q <sub>g</sub>      | V <sub>DS</sub> =30V I <sub>D</sub> =2A<br><br>V <sub>GS</sub> =10V                   | --  | 6.9  | --   | nC   |
| Gate-Source Charge                 | Q <sub>gs</sub>     |                                                                                       | --  | 0.9  | --   | nC   |
| Gate-Drain Charge                  | Q <sub>gd</sub>     |                                                                                       | --  | 1.8  | --   | nC   |
| Drain-Source Diode Characteristics |                     |                                                                                       |     |      |      |      |
| Diode Forward Voltage (Note 3)     | V <sub>SD</sub>     | V <sub>GS</sub> =0V I <sub>S</sub> =2A                                                | --  | 0.79 | 1.2  | V    |
| Diode Forward Current (Note 2)     | I <sub>S</sub>      |                                                                                       | --  | --   | 2    | A    |

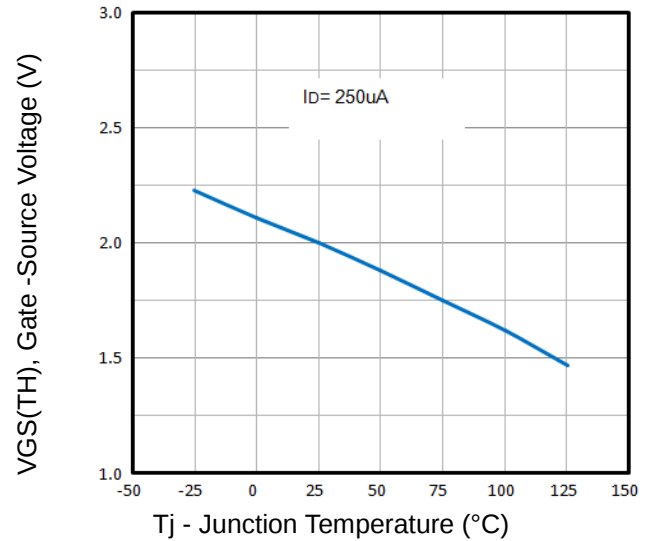
Notes:

- ① Pulse width limited by maximum allowable junction temperature  
 ② Pulse test ; Pulse width≤300μs, duty cycle≤2%.

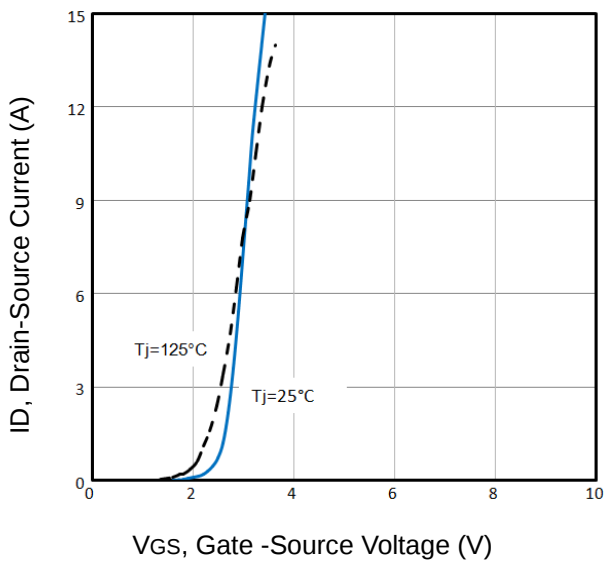
## • Typical Characteristics



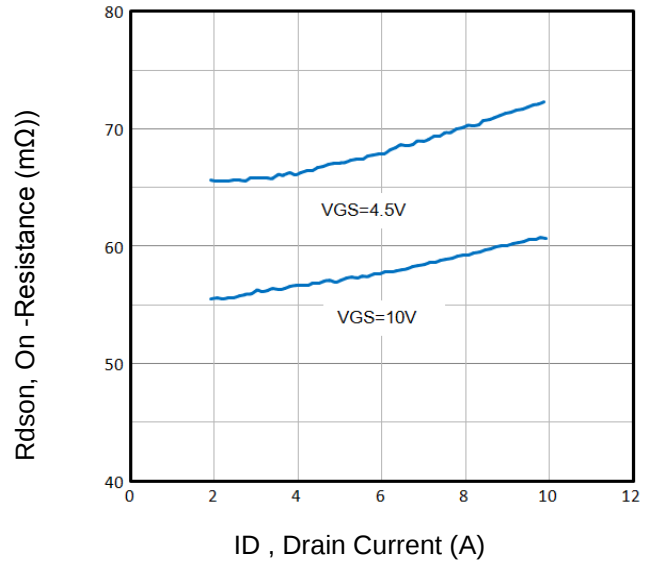
**Fig1.** Typical Output Characteristics



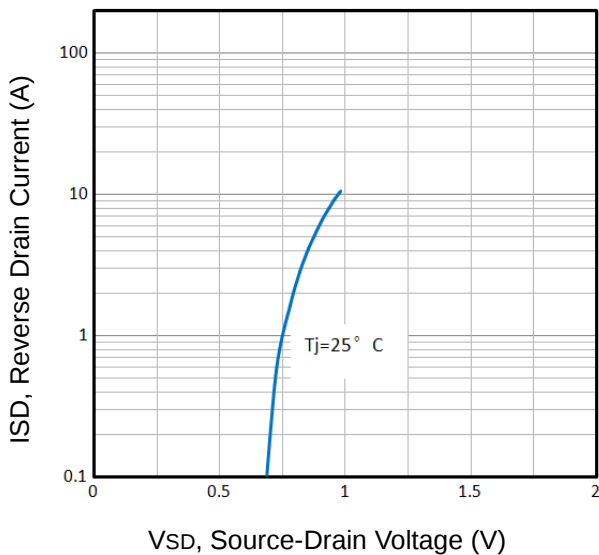
**Fig2.** VGS(TH) Voltage Vs. Temperature



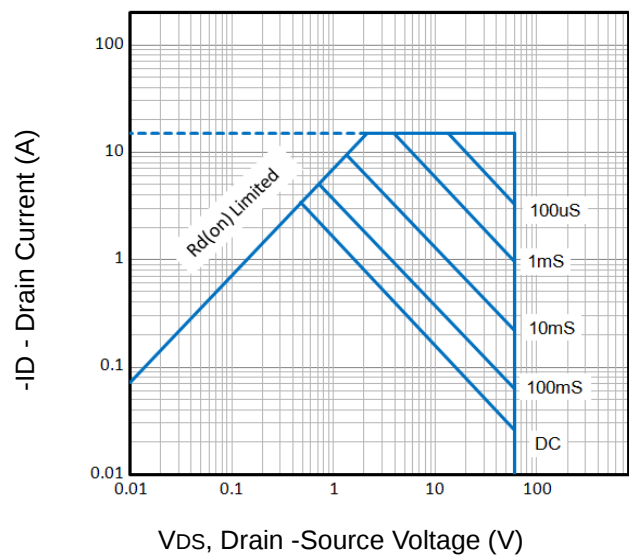
**Fig3.** Typical Transfer Characteristics



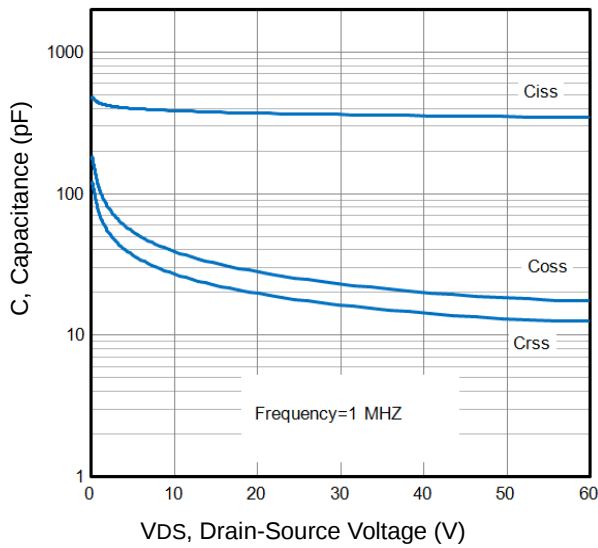
**Fig4.** On-Resistance vs. Drain Current and Gate



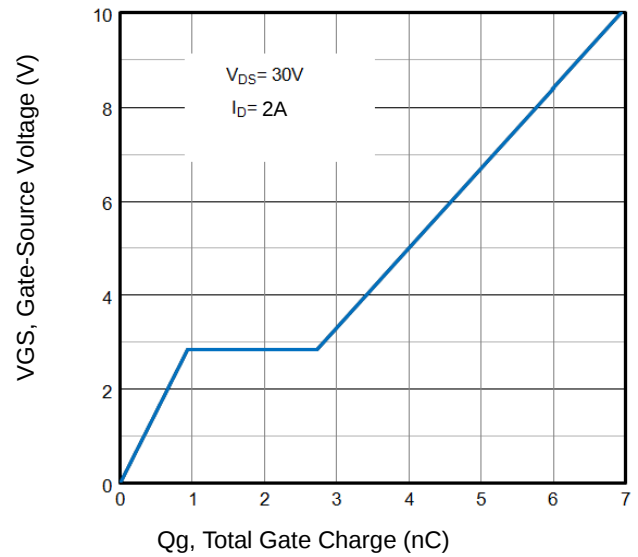
**Fig5.** Typical Source-Drain Diode Forward Voltage



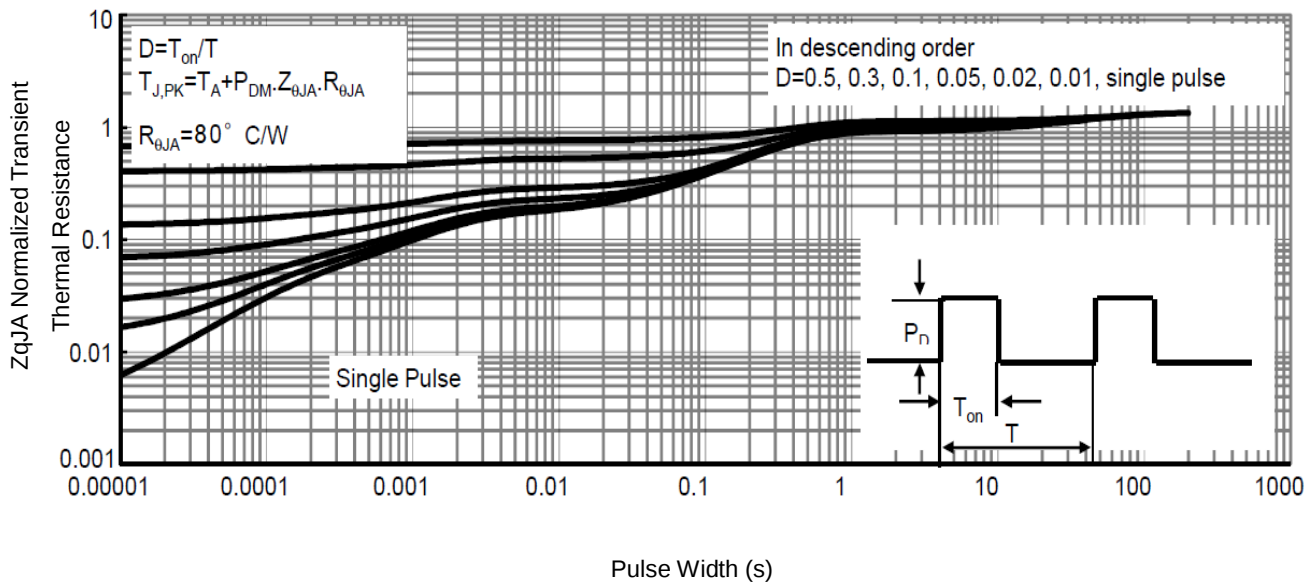
**Fig6.** Maximum Safe Operating Area



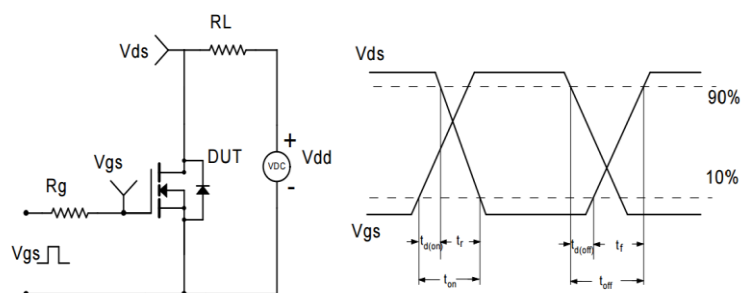
**Fig7.** Typical Capacitance Vs. Drain-Source Voltage



**Fig8.** Typical Gate Charge Vs. Gate-Source Voltage

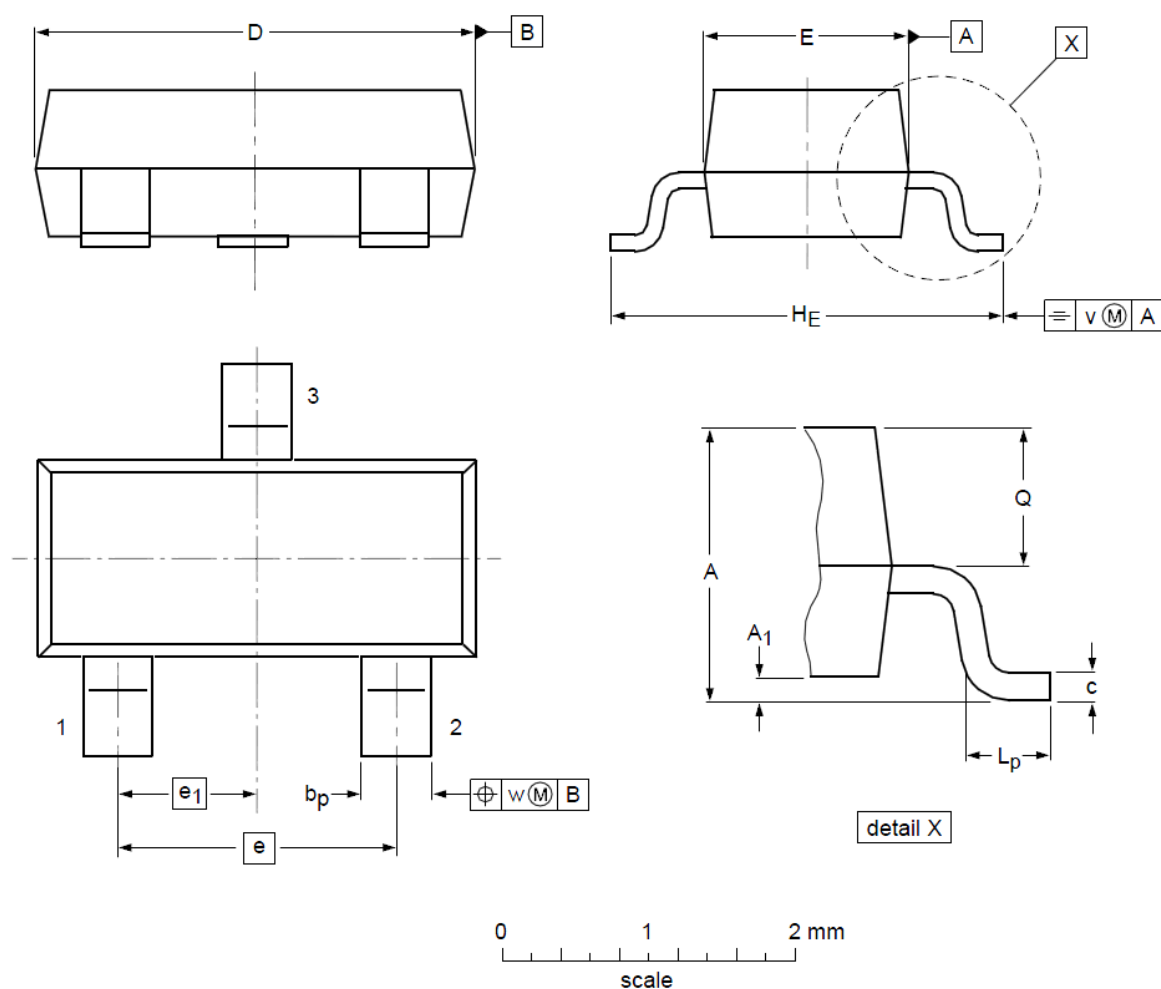


**Fig9.** Normalized Maximum Transient Thermal Impedance



**Fig10.** Switching Time Test Circuit and waveforms

## SOT23-3L Package Outline Dimensions



**DIMENSIONS** ( unit : mm )

| Symbol               | Min  | Typ  | Max  | Symbol               | Min  | Typ  | Max  |
|----------------------|------|------|------|----------------------|------|------|------|
| <b>A</b>             | 0.90 | 1.01 | 1.15 | <b>A<sub>1</sub></b> | 0.01 | 0.05 | 0.10 |
| <b>b<sub>p</sub></b> | 0.30 | 0.42 | 0.50 | <b>c</b>             | 0.08 | 0.13 | 0.15 |
| <b>D</b>             | 2.80 | 2.92 | 3.00 | <b>E</b>             | 1.20 | 1.33 | 1.40 |
| <b>e</b>             | --   | 1.90 | --   | <b>e<sub>1</sub></b> | --   | 0.95 | --   |
| <b>H<sub>E</sub></b> | 2.25 | 2.40 | 2.55 | <b>L<sub>p</sub></b> | 0.30 | 0.42 | 0.50 |
| <b>Q</b>             | 0.45 | 0.49 | 0.55 | <b>v</b>             | --   | 0.20 | --   |
| <b>w</b>             | --   | 0.10 | --   |                      |      |      |      |